NSN 5961-01-351-0528

A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-351-0528 **Inclosure Material:** Metal **Overall Length:** Between 0.755 inches and 0.785 inches **Terminal Length:** Between 0.100 inches and 0.165 inches **Overall Height:** 0.200 inches **Overall Width:** Between 0.245 inches and 0.271 inches **Component Name And Quantity:** 10 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 30.0 nonrepetitive peak reverse voltage all semiconductor device diode and 30.0 nonrepetitive peak off-state voltage all semiconductor device diode **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average preset all semiconductor device diode **Power Rating Per Characteristic:** 650.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 16 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: